# **VOLTAGE TRANSMITTER IC**

### **FEATURES**

- Wide Supply Voltage Range: 6...35V
- Wide Operating Temperature Range: -40°C...+85°C
- Adjustable Voltage Reference: 4.5 to 10V
- Additional Current/Voltage Source
- Instrumentation Amplifier Input (Reversible Polarity)
- Operation Amplifier Input
- Adjustable Gain and Offset
- Adjustable Output Voltage Range: 0.5...4.5V, 0...5/10V, other
- Protection Against Reverse Polarity
- Output Current Limitation

## **APPLICATIONS**

- Industrial Process Control
- Sensor Transmitter (e.g. pressure)
- Voltage Transmitter

#### **GENERAL DESCRIPTION**

The AM401 is a low cost monolithic voltage transmitter, designed for flexible bridge input signal conditioning. The integrated circuit is ideally suited for a wide variety of transducers with an differential output signal. It contains a high accuracy instrumentation amplifier for differential input signals, an operational amplifier output stage, and an adjustable 5 to 10V reference. In addition to these functional elements an auxiliary operational amplifier can be used as a current or voltage source. Output range and gain are adjustable by external resistors. Using the internal instrumentation amplifier the AM401 is a standard sensor transmitter with the possibility to indicate an over range signal. With the freely connectable operational amplifier input this IC can be used as an adjustable voltage-to-voltage transmitter.

### **DELIVERY**

- DIL16 packages (samples)
- SO16(n) packages
- Dice on 5" blue foil

## **BLOCK DIAGRAM+**

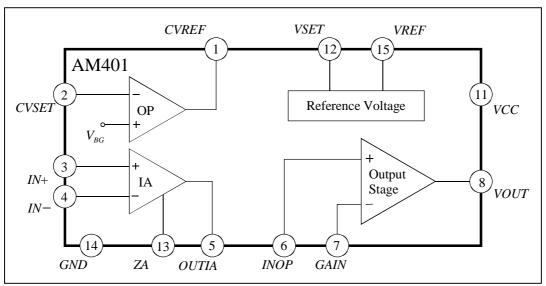


Figure 1

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## **ELECTRICAL SPECIFICATIONS**

 $T_{amb} = 25$ °C,  $V_{CC} = 24$ V,  $V_{REF} = 5$ V,  $I_{REF} = 1$ mA (unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Voltage Range	$V_{CC}$		6		35	V
Quiescent Current	$I_{CC}$	$T_{amb} = -40+85$ °C, $I_{REF} = 0$ mA			1.5	mA
Temperature Specifications		- <b>L</b>				
Operating	$T_{amb}$		-40		85	°C
Storage	$T_{st}$		-55		125	°C
Junction	$T_J$				150	°C
Thermal Resistance	$\Theta_{ja}$	DIL16 plastic package		70		°C/W
	$\Theta_{ja}$	SO16 narrow plastic package		140		°C/W
Voltage Reference		1		•		
Voltage	$V_{REF}$	VSET not connected	4.75	5.00	5.25	V
	$V_{REF}$	$VSET = GND, V_{CC} \ge 11V$	9.5	10.0	10.5	V
Trim Range	$V_{R10}$		4.5		$V_{R10}$	V
Current	$I_{REF}$		0.2		10.0	mA
$V_{REF}$ vs. Temperature	$\mathrm{d}V_{REF}/\mathrm{d}T$	$T_{amb} = -40+85$ °C		±90	±140	ppm/°C
Line Regulation	$\mathrm{d}V_{REF}/\mathrm{d}V$	$V_{CC} = 6V35V$		30	80	ppm/V
	$\mathrm{d}V_{REF}/\mathrm{d}V$	$V_{CC} = 6$ V35V, $I_{REF} \approx 5$ mA		60	150	ppm/V
Load Regulation	$\mathrm{d}V_{REF}/\mathrm{d}I$			0.05	0.10	%/mA
	$\mathrm{d}V_{REF}/\mathrm{d}I$	$I_{REF} \approx 5 \text{mA}$		0.06	0.15	%/mA
Load Capacitance	$C_L$		1.9	2.2	5.0	μF
Current/Voltage Source						
Internal Reference	$V_{BG}$		1.20	1.27	1.35	V
$V_{BG}$ vs. Temperature	$\mathrm{d}V_{BG}/\mathrm{d}T$	$T_{amb} = -40+85^{\circ}\text{C}$		±60	±140	ppm/°C
Current Source: $I_{CV} = V_{BG}/R_{EXT}$						
Adjustable Current Range	$I_{CV}$		0		10	mA
Output Voltage	$V_{CV}$	$V_{CC}$ < 18V	$V_{BG}$		$V_{CC}$ – 5	V
	$V_{CV}$	$V_{CC} \ge 18\text{V}$	$V_{BG}$		13	V
Voltage Source: $V_{CV} = V_{BG}(R_{EXT1} + R_{II})$	$EXT2$ ) / $R_{EXT2}$	•				
Adjustable Voltage Range	$V_{CV}$	V <sub>CC</sub> < 18V	0.4		$V_{CC}$ – 5	V
	$V_{CV}$	$V_{CC} \ge 18 \text{V}$	0.4		13	V
Output Current	$I_{CV}$	Source			10	mA
	$I_{CV}$	Sink			-100	μΑ
Load Capacitance	$C_L$	Source mode	0	1	10	nF
Instrumentation Amplifier						
Internal Gain	$G_{I\!A}$		4.9	5	5.1	
Differential Input Voltage Range	$V_{IN}$		0		±400	mV
Common Mode Input Range	CMIR	$V_{CC}$ < 9V, $I_{CV}$ < 2mA	1.5		$V_{CC}$ – 3	V
	CMIR	$V_{CC} \ge 9V$ , $I_{CV} < 2mA$	1.5		6.0	V
Common Mode Rejection Ratio	CMRR		80	90		dB
Power Supply Rejection Ratio	PSRR		80	90		dB
Offset Voltage	$V_{OS}$			±1.5	±6	mV
$V_{OS}$ vs. Temperature	$\mathrm{d}V_{OS}/\mathrm{d}T$			±5		μV/°C
Input Bias Current	$I_B$			-120	-300	nA
$I_B$ vs. Temperature	$\mathrm{d}I_B/\mathrm{d}T$			-0.35	-0.8	nA/°C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Instrumentation Amplifier (cont.)						
Output Voltage Range	$V_{OUTIA}$	$V_{CC} < 9V, R_{LIA} \le 10k\Omega$	0*		$V_{CC}$ – 3	V
	$V_{OUTIA}$	$V_{CC} \ge 9V$ , $R_{LIA} \le 10$ k $\Omega$	0*		6	V
Minimum Output Voltage	$V_{OUTIAmin}$	without external load resistance $R_{LIA}$		5	17	mV
Load Capacitance	$C_L$				250	pF
Zero Adjust Stage						
Internal Gain	$G_{ZA}$			1		
Input Voltage	$V_{ZA}$	$V_{ZA} \le V_{OUTIA} - G_{IA} V_{IN}$	0		$V_{OUTIA}$	V
Offset Voltage	$V_{OS}$			±0.5	±2.0	mV
$V_{OS}$ vs. Temperature	$\mathrm{d}V_{OS}/\mathrm{d}T$			±1.6	±5	μV/°C
Input Bias Current	$I_B$			38	100	nA
$I_B$ vs. Temperature	$\mathrm{d}I_B/\mathrm{d}T$			24	75	pA/°C
Voltage Output Stage						
Adjustable Gain	$G_{OP}$		1			
Input Range	IR	$V_{CC} < 10 \text{V}$	0		$V_{CC}$ – 5	V
	IR	$V_{CC} \ge 10 \text{V}$	0		5	V
Power Supply Rejection Ratio	PSRR		80	90		dB
Offset Voltage	$V_{OS}$			±0.5	±2	mV
$V_{OS}$ vs. Temperature	$\mathrm{d}V_{OS}/\mathrm{d}T$			±3	±7	μV/°C
Input Bias Current	$I_B$			5	12	nA
$I_B$ vs. Temperature	$\mathrm{d}I_B/\mathrm{d}T$			3.5	10	pA/°C
Output Voltage Range	$V_{OUT}$	$V_{CC} < 18V$	0		$V_{CC}$ – 5	V
	$V_{OUT}$	$V_{CC} \ge 18V$	0		13	V
Output Current Limitation	$I_{LIM}$	$V_{OUT} \ge 10$ V	5	7	10	mA
Output Current	$I_{OUT}$		0		$I_{LIM}$	mA
Load Resistance	$R_L$		2			kΩ
Load Capacitance	$C_L$				500	nF
<b>Protection Functions</b>						
Protection against reverse polarity		Ground vs. $V_S$ vs. $V_{OUT}$			35	V
System Parameters						
Nonlinearity		ideal input		0.05	0.15	%FS

<sup>\*</sup> Depending on external load resistance at output of IA ( $R_{LIA} \le 10 \text{k}\Omega \Rightarrow V_{OUTIA} < 3 \text{mV}$ ); internal load resistance is  $\approx 100 \text{k}\Omega$  Currents flowing into the IC are negative

## **BOUNDARY CONDITIONS**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Sum Gain Resistors	$R_1 + R_2$	only for sink mode of CV reference	90		200	kΩ
Sum Offset Resistors	$R_3 + R_4$		20		200	kΩ
$V_{REF}$ Capacitance	$C_1$		1.9	2.2	5.0	μF
V <sub>IA</sub> Capacitance	$C_2$		10		100	nF

### **FUNCTIONAL DIAGRAM**

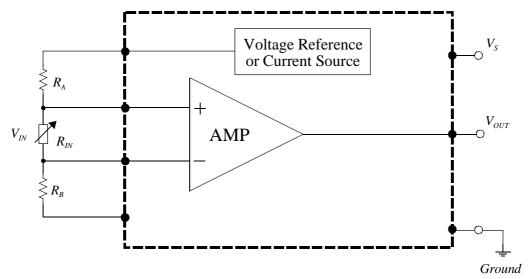


Figure 2

### **FUNCTIONAL DESCRIPTION**

The IC AM401 is an integrated voltage transmitter for bridge input signals. With variations of a few external components the output voltage can be adjusted over a wide range. In addition to the resistors  $R_1$  and  $R_2$  the circuitry needs only two external capacitors  $C_1$  and  $C_2$  for a basic application. Using the input of the voltage output stage the AM401 can be used for single ended input signals as well. Typical values for the external components are listed in the *Application Notes*.

Basically the AM401 consists of 4 functional blocks as they are shown in Figure 1:

- 1. A high accuracy *instrumentation amplifier* with an internal gain  $G_{IA}$  and the possibility to adjust the bias voltage (pin ZA) for differential input signals.
- 2. An *operational amplifier output stage* used for voltage transmission and as the voltage output. The output stage has an output current limitation protecting the IC.
- 3. An *adjustable voltage reference* (VSET = N.C. or VSET = GND) can be used as an excitation for constant voltage sensors or as supply for other external devices.
- 4. An *auxiliary operational amplifier* which can used as a additional current/voltage source or as an adjustment for the bias offset voltage (see *Application Notes*).

The transfer function of the output voltage of the instrumentation amplifier is:

$$V_{OUTIA} = G_{IA}V_{IN} + V_{ZA}$$

with the an offset voltage  $V_{ZA}$  which can be adjusted on the zero adjust pin ZA. Using a circuitry with the additional operational amplifier like shown in figure 7, this offset voltage can be calculated by

# **VOLTAGE TRANSMITTER IC**

**AM401** 

$$V_{OFFSET} = V_{BG} - \frac{R_4}{R_3} (V_{REF} - V_{BG})$$

For the entire output voltage  $V_{OUT}$  of the IC is valid

$$V_{OUT} = G_{OP} \cdot V_{INOP}$$

with the adjustable gain  $G_{OP}$ 

$$G_{OP} = \frac{R_1}{R_2} + 1$$

The minimum supply voltage, which has to be adjusted, can be calculated by

$$V_S \ge V_{OUTmax} + 5V$$

**Important:** Non used blocks of the IC like the auxiliary OP in Application 1 have to be connected. The two capacitors  $C_1$  and  $C_2$  have to be connected in every case as well! Even if the voltage reference is not used.

## **PINOUT**

CURE	. ()	40 N.C
CVREF	1 –	16 <i>□ N.C</i> .
$CVSET \square $	2	15 VREF
$IN+ \square$ :	3	14
IN-	4	13 <i>ZA</i>
OUTIA 🗌 :	5	12 <i>VSET</i>
INOP	6	11 <i>VCC</i>
GAIN	7	10 <i>N.C.</i>
VOUT 🗆	8	9 □ <i>N.C</i> .

Figure 3

PIN	NAME	DESIGNATION
1	CVREF	Current/Voltage Reference
2	CVSET	Set Current/Voltage
3	IN+	Non Inverting Bridge Input
4	IN-	Inverting Bridge Input
5	OUTIA	Output Instrumentation Amplifier
6	INOP	Input Operational Amplifier
7	GAIN	Gain Adjustment
8	VOUT	Voltage Output
9	<i>N.C.</i>	Not Connected
10	N.C.	Not Connected
11	VCC	Supply Voltage
12	VSET	Voltage Select
13	ZA	Zero Adjust
14	GND	IC Ground
15	VREF	Reference Voltage
16	N.C.	Not Connected

## **DELIVERY**

The AM401 is available in version:

- 16 pin DIL packages (samples)
- SO 16 (n) packages
- Dice on 5" blue foil

## PACKAGE DIMENSIONS SO16 (n)

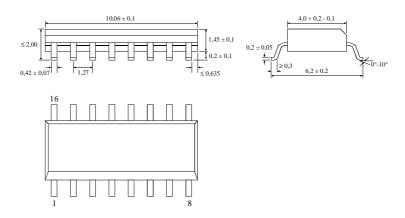


Figure 4

## **APPLICATION FOR OUTPUT VOLTAGE 0...10V**

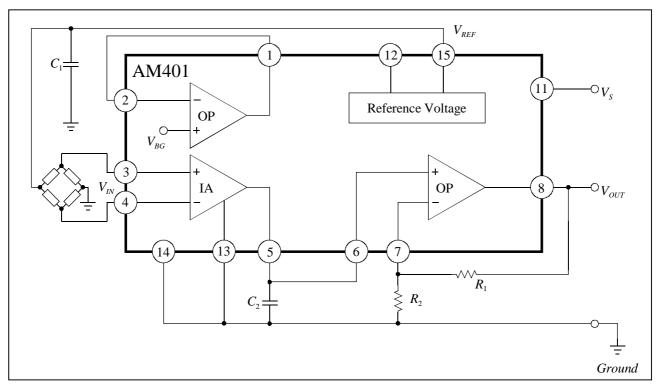


Figure 5

Used in a 0...10V output application zero adjust pin 13 (ZA) is connected to Ground (Figure 5). The Gain G is adjusted by external resistors  $R_1$  and  $R_2$  and can be calculated by

$$G = G_{IA}G_{OP} = G_{IA}(1 + R_1/R_2)$$

The transfer function of the output voltage  $V_{OUT}$  becomes

$$V_{OUT} = G V_{IN}$$

With these equations the external resistors  $R_1$  and  $R_2$  can be adjusted

$$\frac{R_1}{R_2} = \frac{V_{OUT}}{G_{IA} V_{IN}} - 1$$

**Example 1:** Output voltage range 0...10V

In this case the values of the external devices ( $V_{IN} = 0...50$ mV,  $R_1/R_2 = 39$ ) are as follows

$$R_1 \approx 39 \text{k}\Omega$$

$$R_2 \approx 1 \text{k}\Omega$$

$$G_{\rm tot} = 5$$

$$R_2 \approx 1 \text{k}\Omega$$
  $G_{IA} = 5$   $C_1 = 2.2 \mu\text{F}$   $C_2 = 10 \text{nF}$ 

$$C_2 = 10 \text{nF}$$

**Example 2:** Output voltage range 0...5V

In this case the values of the external devices ( $V_{IN} = 0...100$ mV,  $R_1/R_2 = 9$ ) are as follows

$$R_1 \approx 90 \text{kO}$$

$$R_2 \approx 10 \text{kO}$$

$$G_{IA} = 5$$

$$R_1 \approx 90 \text{k}\Omega$$
  $R_2 \approx 10 \text{k}\Omega$   $G_{IA} = 5$   $C_1 = 2.2 \mu\text{F}$   $C_2 = 10 \text{nF}$ 

$$C_2 = 10 \text{nF}$$

## **APPLICATION FOR CURRENT DRIVEN SENSORS**

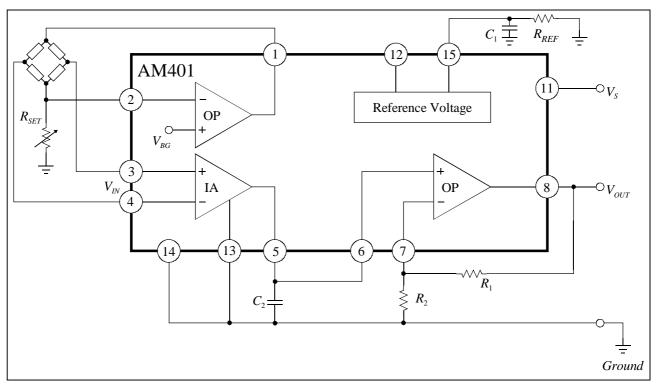


Figure 6

In this application the auxiliary operational amplifier is used as a current source. The values of the external components are calculated for an 0...5V output. For the application the zero adjust pin 13 (ZA) is connected to Ground (Figure 5). The Gain G is adjusted by external resistors  $R_1$  and  $R_2$  and can be calculated by

$$G = G_{IA}G_{OP} = G_{IA}(1 + R_1/R_2)$$

The transfer function of the output voltage  $V_{OUT}$  becomes

$$V_{OUT} = G V_{IN}$$

With these equations the external resistors  $R_1$  and  $R_2$  can be adjusted

$$\frac{R_1}{R_2} = \frac{V_{OUT}}{G_{IA} V_{IN}} - 1$$

The excitation current of for the sensor can be calculated over

$$I_S = \frac{V_{BG}}{R_{SET}}$$

**Example 3:** Output voltage range 0...5V

The values of the external devices ( $V_{IN} = 0...100$ mV,  $R_1/R_2 = 9$ ,  $I_S = 1.5$ mA,  $V_{BG} = 1.27$ V) are

 $R_1 \approx 90 \text{k}\Omega$ 

 $R_2 \approx 10 \mathrm{k}\Omega$ 

 $G_{IA} = 5$   $C_1 = 2.2 \mu F$   $C_2 = 10 n F$ 

 $R_{SET} \approx 846.7\Omega$   $R_{REF} \approx 22 \text{k}\Omega$ 

## APPLICATION FOR OUTPUT VOLTAGE 0.5...4.5V

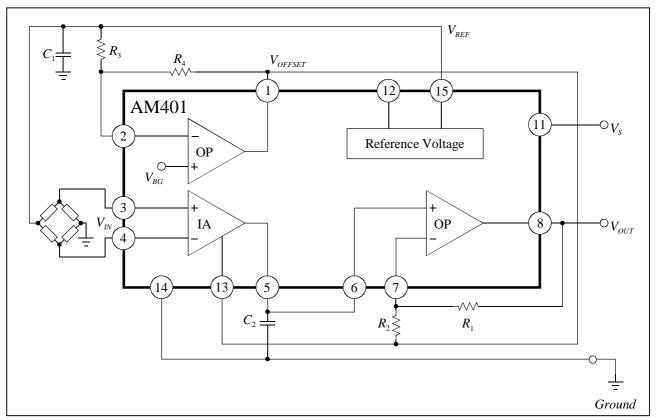


Figure 7

Used in a 0.5...4.5V output application zero adjust pin 13 (ZA) is connected to an offset voltage  $V_{OFFSET}$  (Figure 6). The Gain G is adjusted by external resistors  $R_1$  and  $R_2$  and can be calculated by

$$G = G_{IA}G_{OP} = G_{IA}(1 + R_1/R_2)$$

The transfer function of the output voltage  $V_{OUT}$  becomes

$$V_{OUT} = G V_{IN} + V_{OFFSET}$$

The offset voltage can be calculated by

$$V_{OFFSET} = V_{BG} - \frac{R_4}{R_3} \left( V_{REF} - V_{BG} \right) \quad \Rightarrow \quad \frac{R_3}{R_4} = \frac{V_{REF} - V_{BG}}{V_{BG} - V_{OFFSET}}$$

With these equations the external resistors  $R_1$  and  $R_2$  can be adjusted

$$\frac{R_1}{R_2} = \frac{V_{OUT} - V_{OFFSET}}{G_{IA} V_{IN}} - 1$$

Example 4: Output voltage range 0.5...4.5V

In this case the values of the external devices ( $V_{IN} = 0...250$ mV,  $V_{REF} = 5$ V,  $R_1/R_2 = 2.2$ ,  $R_3/R_4 = 5$ ) are as follows

$$R_1 \approx 100 \mathrm{k}\Omega$$

$$R_2 \approx 47 \mathrm{k}\Omega$$

$$R_3 \approx 75 \mathrm{k}\Omega$$

$$R_4 \approx 15 \mathrm{k}\Omega$$

$$V_{OFFSET} = 0.5 \text{V}$$

$$R_2 \approx 47 \text{k}\Omega$$
  
 $C_1 = 2.2 \mu\text{F}$ 

$$C_2 = 10$$
nF

## **TOPOLOGIE FOR THE 0...10V APPLICATION**

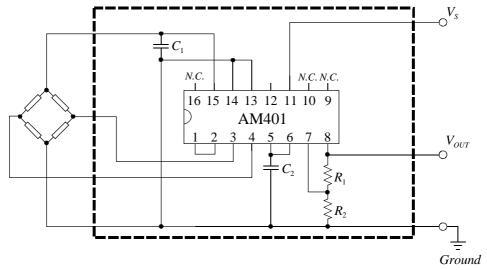


Figure 8

## **TOPOLOGIE FOR THE 0.5...4.5V APPLICATION**

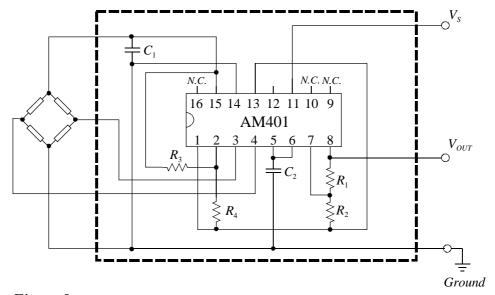


Figure 9

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